



SLPS269A - JUNE 2010-REVISED JULY 2011

P-Channel NexFET[™] Power MOSFET

Check for Samples: CSD25201W15

FEATURES

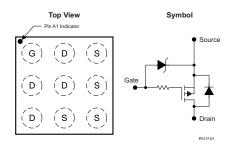
- Low Resistance
- Small Footprint 1.5-mm × 1.5-mm
- Gate ESD Protection –3kV
- Pb Free
- RoHS Compliant
- Halogen Free
- Gate-Source Voltage Clamp

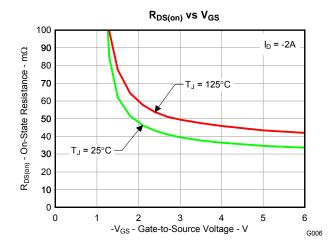
APPLICATIONS

- Battery Management
- Battery Protection

DESCRIPTION

The device has been designed to deliver the lowest on resistance and gate charge in the smallest outline possible with excellent thermal characteristics in an ultra low profile. Low on resistance coupled with the small footprint and low profile make the device ideal for battery operated space constrained applications.





PRODUCT SUMMARY

V _{DS}	Drain to Drain Voltage	-20		V
Qg	Gate Charge Total (-4.5V)	4.3		nC
Q _{gd}	Gate Charge Gate to Drain	0.7		nC
	Drain to Source On Resistance	$V_{GS} = -1.8V$	52	mΩ
R _{DS(on)}		$V_{GS} = -2.5V$	42	mΩ
		V _{GS} = -4.5V 33		mΩ
V _{GS(th)}	Threshold Voltage	-0.7		V

ORDERING INFORMATION

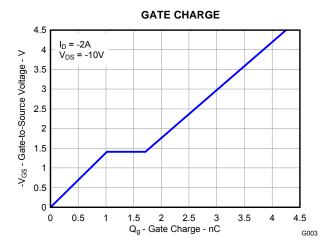
Device	Package	Media	Qty	Ship
CSD25201W15	1.5-mm × 1.5-mm Wafer Level Package	7-Inch Reel	3000	Tape and Reel

ABSOLUTE MAXIMUM RATINGS

$T_A = 28$	5°C unless otherwise stated	VALUE	UNIT
V _{DS}	Drain to Source Voltage	-20	V
V_{GS}	Gate to Source Voltage	-6	V
	Continuous Drain Current ⁽¹⁾⁽²⁾	4	А
ID	Pulsed Drain Current ⁽¹⁾⁽²⁾	4	А
	Continuous Gate Current ⁽¹⁾⁽²⁾	0.5	А
I _G	Pulsed Gate Current ⁽¹⁾⁽²⁾	7	А
PD	Power Dissipation ⁽¹⁾	1.5	W
T _J , T _{STG}	Operating Junction and Storage Temperature Range	-55 to 150	°C

(1) Based on Min Cu footprint

(2) Ball limited



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

$(T_A = 25^{\circ}C \text{ unless otherwise stated})$

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	haracteristics	•	·		,	
BV _{DSS}	Drain to Source Voltage	$V_{GS} = 0V, I_{DS} = -250\mu A$	-20			V
BV _{GSS}	Gate to Source Voltage	$V_{DS} = 0V, I_G = -250\mu A$	-6.1		-7.2	V
I _{DDS}	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = -16V$			-1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = -6V$			-100	nA
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = -250 \mu A$	-0.4	-0.7	-1.1	V
		$V_{GS} = -1.8V, I_{DS} = -2A$		52	70	mΩ
R _{DS(on)}	Drain to Source On Resistance	$V_{GS} = -2.5V, I_{DS} = -2A$		42	50	mΩ
		$V_{GS} = -4.5V, I_{DS} = -2A$		33	40	mΩ
g _{fs}	Transconductance	$V_{DS} = -10V, I_{DS} = -2A$		12		S
Dynamic	c Characteristics				·	
C _{ISS}	Input Capacitance			490	640	pF
C _{OSS}	Output Capacitance	$V_{GS} = 0V, V_{DS} = -10V,$ f = 1MHz		215	280	pF
C _{RSS}	Reverse Transfer Capacitance			70	91	pF
R _G	Series Gate Resistance ⁽¹⁾			26	35	Ω
Qg	Gate Charge Total (-4.5V)			4.3	5.6	nC
Q _{gd}	Gate Charge - Gate to Drain	$V_{DS} = -10V,$ $I_{O} = -2A$		0.7		nC
Q _{gs}	Gate Charge - Gate to Source			1		nC
Q _{g(th)}	Gate Charge at Vth			0.3		nC
Q _{OSS}	Output Charge	$V_{DS} = -9.5V, V_{GS} = 0V$		3.1		nC
t _{d(on)}	Turn On Delay Time ⁽²⁾			9.5		ns
t _r	Rise Time ⁽²⁾	$V_{DS} = -10V, V_{GS} = -4.5V,$		11		ns
t _{d(off)}	Turn Off Delay Time ⁽²⁾	$I_{DS} = -2A, R_G = 2\Omega$		51		ns
t _f	Fall Time ⁽²⁾			38		ns
Diode Cl	haracteristics					
V _{SD}	Diode Forward Voltage	$I_{DS} = -2A, V_{GS} = 0V$		0.7	1	V
Q _{rr}	Reverse Recovery Charge	$V_{DD} = -9.5V, I_F = -2A,$		5.7		nC
t _{rr}	Reverse Recovery Time	di/dt = 200A/µs		10		ns

Includes gate clamp resistor (1)

External R_G is in addition to the internal gate clamp resistor (2)

THERMAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

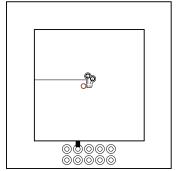
PARAMETER		MIN	TYP	MAX	UNIT
D	Junction to Ambient Thermal Resistance ⁽¹⁾			283	°C/W
R _{θJA}	Junction to Ambient Thermal Resistance ⁽²⁾			185	°C/W

(1)

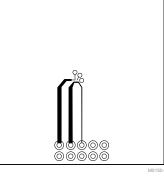
Device mounted on FR4 material with minimum Cu mounting area. Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu. (2)



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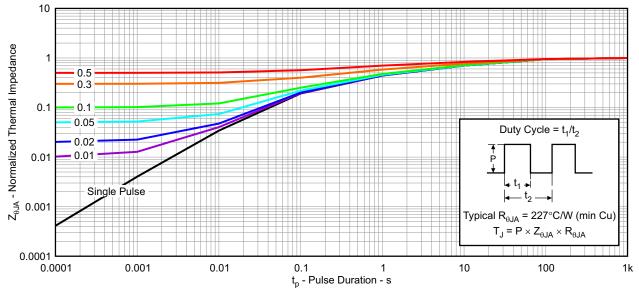
Max $R_{\theta JA} = 185^{\circ}C/W$ when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max $R_{\theta JA} = 283^{\circ}C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

TYPICAL MOSFET CHARACTERISTICS

 $T_A = 25^{\circ}C$, unless stated otherwise.



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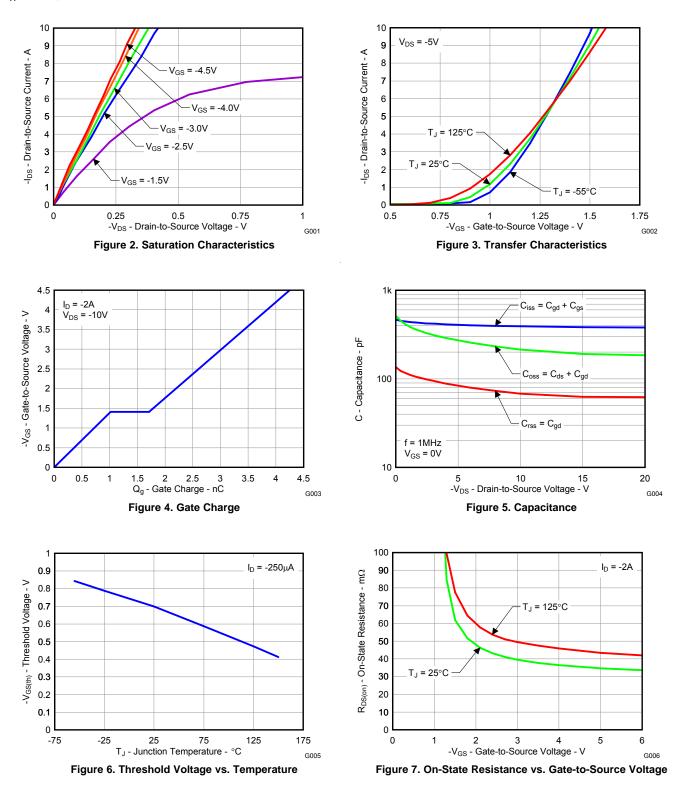
Figure 1. Transient Thermal Impedance

ISTRUMENTS

ÈXAS

TYPICAL MOSFET CHARACTERISTICS (continued)

 $T_A = 25^{\circ}C$, unless stated otherwise.





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TYPICAL MOSFET CHARACTERISTICS (continued)

 $T_A = 25^{\circ}C$, unless stated otherwise.

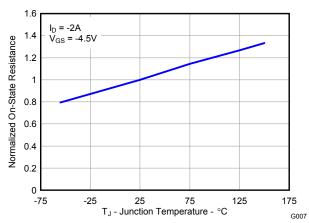
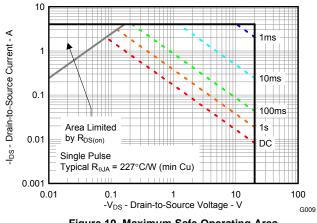
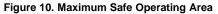


Figure 8. Normalized On-State Resistance vs. Temperature





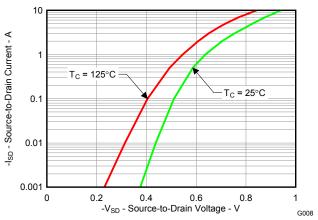


Figure 9. Typical Diode Forward Voltage

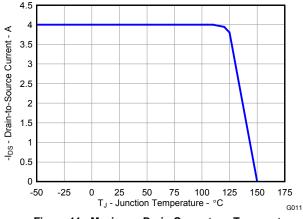


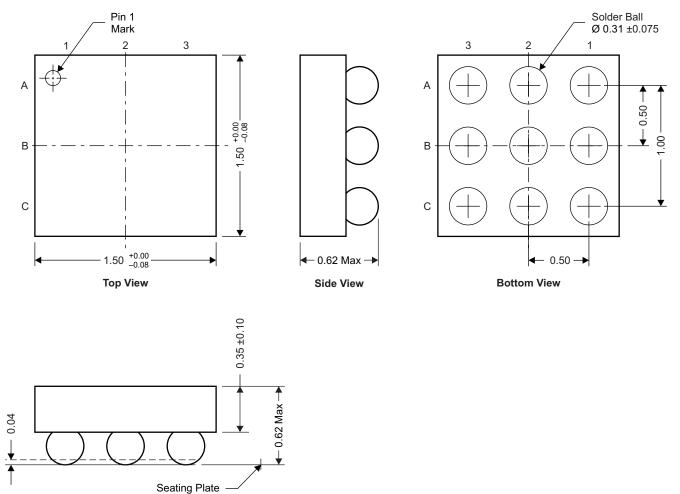
Figure 11. Maximum Drain Current vs. Temperature

TEXAS INSTRUMENTS

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MECHANICAL DATA

CSD25201W15 Package Dimensions



Front View

M0171-01

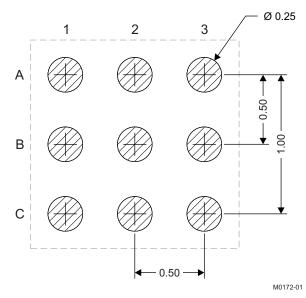
NOTE: All dimensions are in mm (unless otherwise specified)

Pinout

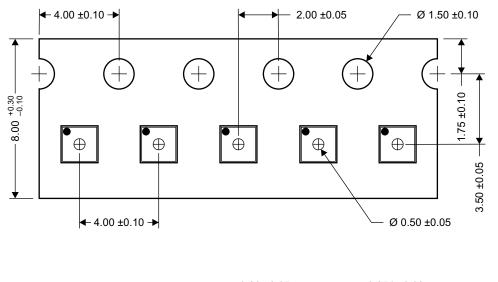
DESIGNATION	
Gate	
Drain	
Source	



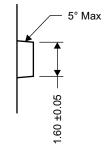
Recommended Land Pattern

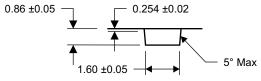


NOTE: All dimensions are in mm (unless otherwise specified)



Tape and Reel Information





M0173-01

- NOTES: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
 - 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
 - 3. Material: black static-dissipative polystyrene
 - 4. All dimensions are in mm (unless otherwise specified)
 - 5. Thickness: 0.30 ±0.05mm
 - 6. MSL1 260°C (IR and convection) PbF reflow compatible

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REVISION HISTORY

Changes from	Original (June	e 2010) to	Revision A
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